NSN 5961-01-364-1983

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Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-364-1983 **Inclosure Material:** Metal **Overall Length:** 1.687 inches **Terminal Length:** 0.312 inches **Overall Height:** 1.197 inches **Overall Width:** 0.875 inches **End Application:** 6625-01-249-3366 **Mounting Facility Quantity: Mounting Method:** Unthreaded hole **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 600.0 repetitive peak off-state voltage **Current Rating Per Characteristic:** 40.00 amperes drain current horsepower metric and 370.00 amperes drain current watts **Power Rating Per Characteristic:** 40.0 watts any acceptable blank and 1.0 watts any acceptable universal **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius ambient air **Terminal Type And Quantity:** 3 tab, solder lug Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: